

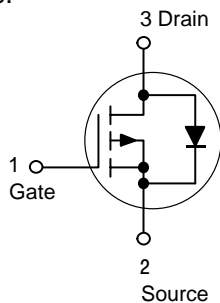
Power MOSFET

130 mAmps, 50 Volts

P-Channel SOT-323

These miniature surface mount MOSFETs reduce power loss conserve energy, making this device ideal for use in small power management circuitry. Typical applications are dc-dc converters, load switching, power management in portable and battery-powered products such as computers, printers, cellular and cordless telephones.

- Energy Efficient
- Miniature SOT-323 Surface Mount Package Saves Board Space
- Pb-Free Package is available.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



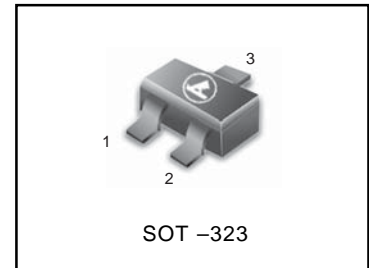
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 3.) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation Alumina Substrate, (Note 4.) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

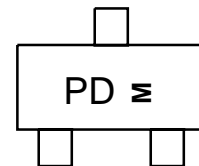
MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSS}	50	V_{dc}
Gate-to-Source Voltage – Continuous	V_{GS}	± 20	V_{dc}
Drain Current			mA
– Continuous @ $T_A = 25^\circ\text{C}$	I_D	130	
– Pulsed Drain Current ($t_p \leq 10 \mu\text{s}$)	I_{DM}	520	
Total Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	225	mW
Operating and Storage Temperature Range	T_J, T_{stg}	- 55 to 150	$^\circ\text{C}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Maximum Lead Temperature for Soldering Purposes, for 10 seconds	T_L	260	$^\circ\text{C}$

LBSS84WT1G
S-LBSS84WT1G



Marking Diagram



PD = Device Code
M = Month Code

ORDERING INFORMATION

Device	Package	Shipping
LBSS84WT1G S-LBSS84WT1G	SOT-323	3000/Tape&Reel
LBSS84WT1G S-LBSS84WT1G	SOT-323	10000/Tape&Reel

LBSS84WT1G , S-LBSS84WT1G

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Drain-to-Source Breakdown Voltage (V _{GS} = 0 Vdc, I _D = 250 μAdc)	V _{(BR)DSS}	50	-	-	Vdc
Zero Gate Voltage Drain Current (V _{DS} = 25 Vdc, V _{GS} = 0 Vdc) (V _{DS} = 50 Vdc, V _{GS} = 0 Vdc) (V _{DS} = 50 Vdc, V _{GS} = 0 Vdc, T _J = 125°C)	I _{DSS}	-	-	0.1 15 60	μAdc
Gate-Body Leakage Current (V _{GS} = ± 20 Vdc, V _{DS} = 0 Vdc)	I _{GSS}	-	-	±10	nAdc

ON CHARACTERISTICS (Note 1.)

Gate-Source Threshold Voltage (V _{DS} = V _{GS} , I _D = 250 μAdc)	V _{GS(th)}	0.8	-	2.0	Vdc
Static Drain-to-Source On-Resistance (V _{GS} = 5.0 Vdc, I _D = 100 mAdc)	r _{DS(on)}	-	5.0	10	Ohms
Transfer Admittance (V _{DS} = 25 Vdc, I _D = 100 mAdc, f = 1.0 kHz)	y _{fs}	50	-	-	mS

DYNAMIC CHARACTERISTICS

Input Capacitance	(V _{DS} = 5.0 Vdc)	C _{iss}	-	30	-	pF
Output Capacitance	(V _{DS} = 5.0 Vdc)	C _{OSS}	-	10	-	
Transfer Capacitance	(V _{DG} = 5.0 Vdc)	C _{rss}	-	5.0	-	

SWITCHING CHARACTERISTICS (Note 2.)

Turn-On Delay Time	(V _{DD} = -15 Vdc, I _D = -2.5 Adc, R _L = 50 Ω)	t _{d(on)}	-	2.5	-	ns
Rise Time		t _r	-	1.0	-	
Turn-Off Delay Time		t _{d(off)}	-	16	-	
Fall Time		t _f	-	8.0	-	
Gate Charge		Q _T	-	6000	-	pC

SOURCE-DRAIN DIODE CHARACTERISTICS

Continuous Current	I _S	-	-	0.130	A
Pulsed Current	I _{SM}	-	-	0.520	
Forward Voltage (Note 2.)	V _{SD}	-	2.5	-	V

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
2. Switching characteristics are independent of operating junction temperature.

TYPICAL ELECTRICAL CHARACTERISTICS

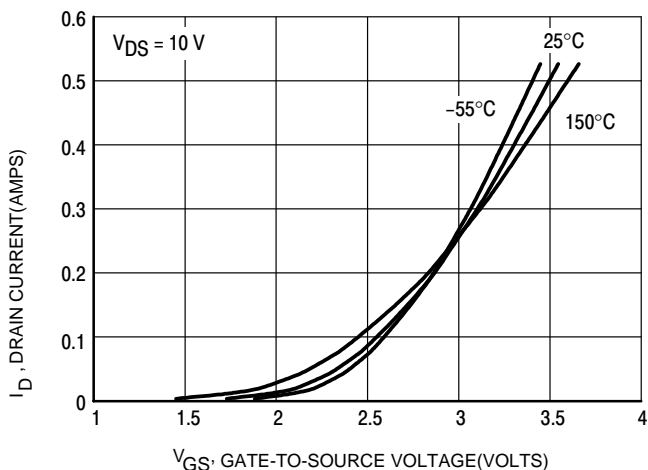


Figure 1. Transfer Characteristics

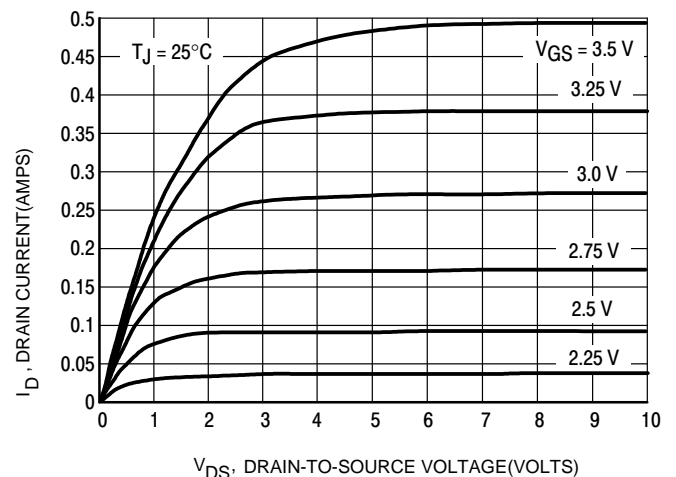


Figure 2. On-Region Characteristics

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TYPICAL ELECTRICAL CHARACTERISTICS

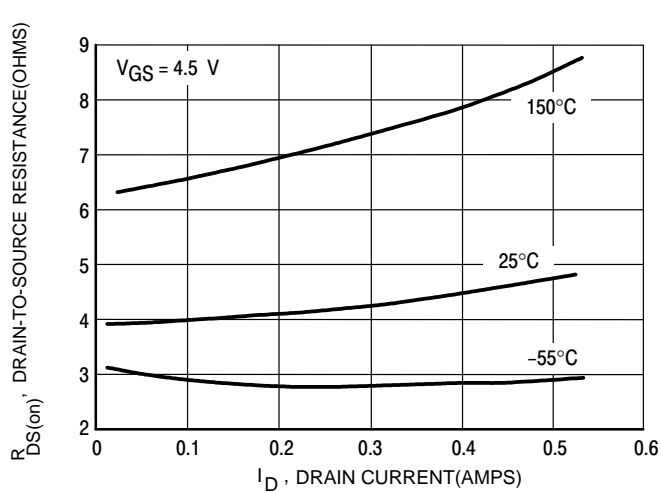


Figure 3. On-Resistance versus Drain Current

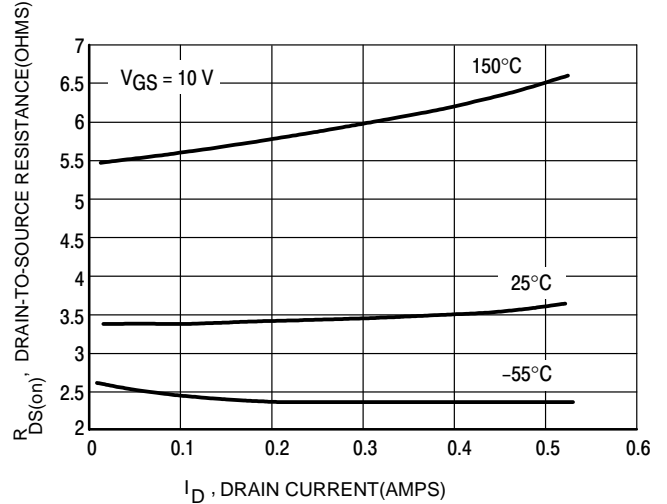


Figure 4. On-Resistance versus Drain Current

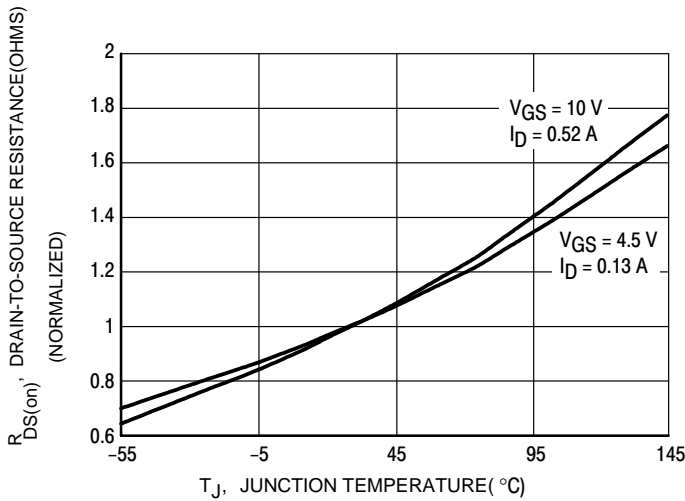


Figure 5. On-Resistance Variation with Temperature

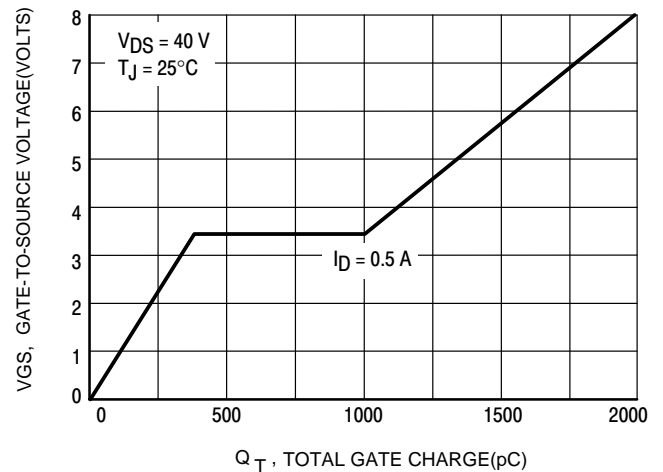


Figure 6. Gate Charge

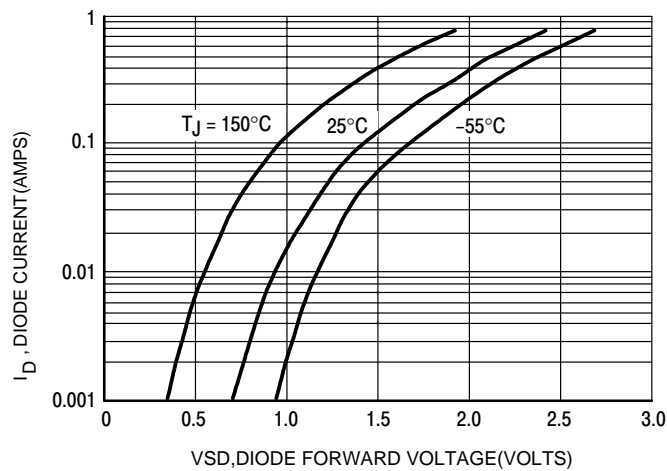
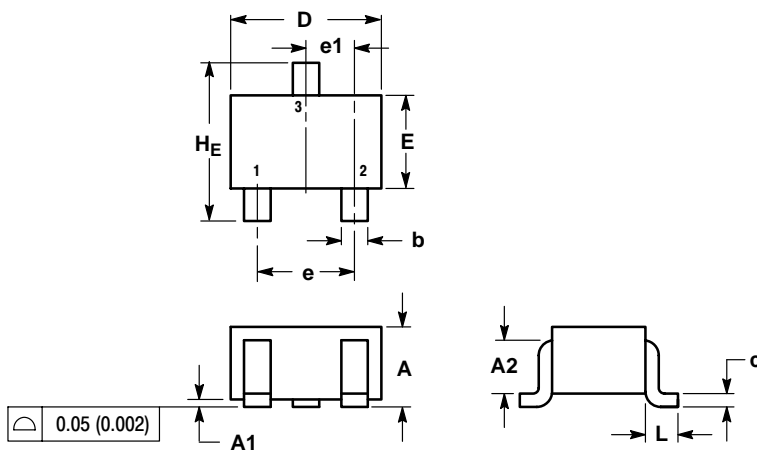


Figure 7. Body Diode Forward Voltage

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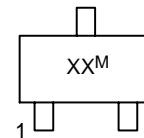
SC-70 (SOT-323)



NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

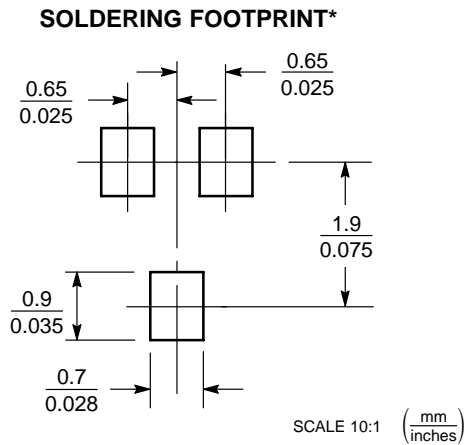
DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.7 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.425 REF			0.017 REF		
HE	2.00	2.10	2.40	0.079	0.083	0.095

GENERIC MARKING DIAGRAM

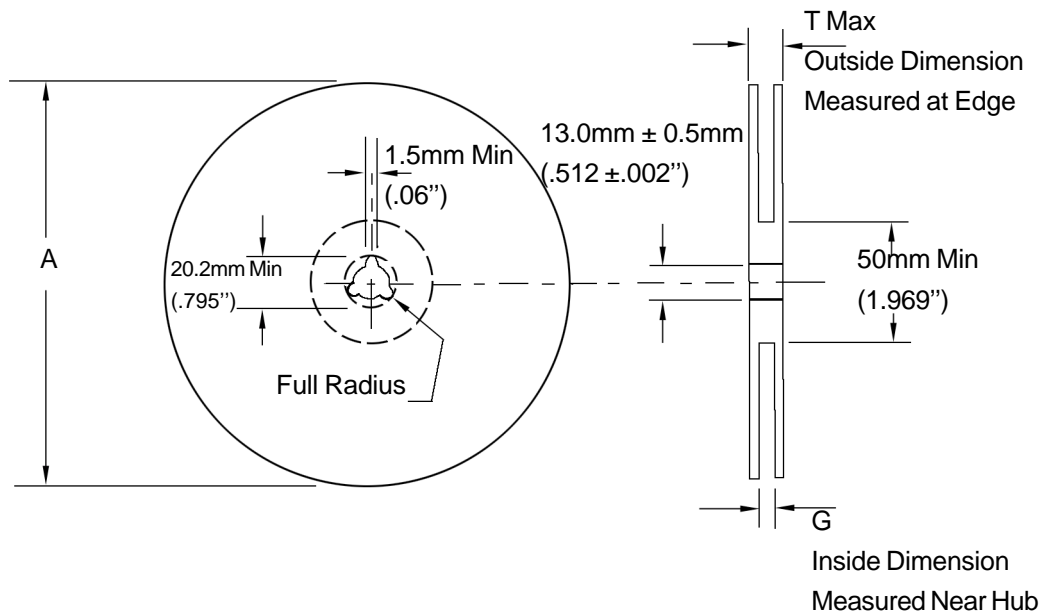


- XX = Specific Device Code
- M = Date Code
- = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.



EMBOSSED TAPE AND REEL DATA FOR DISCRETES



Size	A Max	G	T Max
8 mm	330mm (12.992")	8.4mm+1.5mm, -0.0 (.33"+.059", -0.00)	14.4mm (.56")
12mm	330mm (12.992")	12.4mm+2.0mm, -0.0 (.49 "+ .079", -0.00)	18.4mm (.72")
16mm	360mm (14.173")	16.4mm+2.0mm, -0.0 (.646"+.078", -0.00)	22.4mm (.882")
24 mm	360mm (14.173")	24.4mm+2.0mm, -0.0 (.961"+.070", -0.00)	30.4mm (1.197")

Reel Dimensions

Metric Dimensions Govern — English are in parentheses for reference only

Storage Conditions

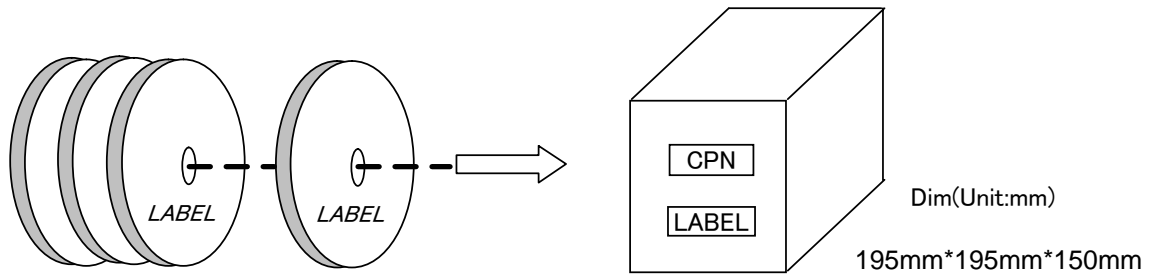
Temperature: 5 to 40 Deg.C (20 to 30 Deg. C is preferred)

Humidity: 30 to 80 RH (40 to 60 is preferred)

Recommended Period: One year after manufacturing

(This recommended period is for the soldering condition only. The characteristics and reliabilities of the products are not restricted to this limitation)

Shipment Specification

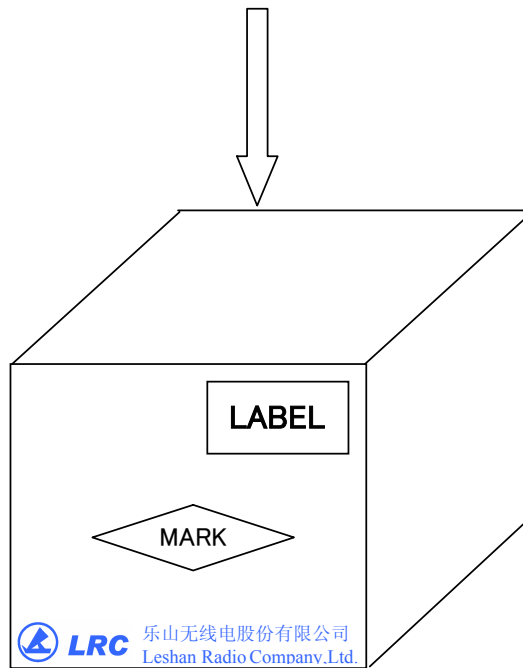


10 Reel

3000PCS/Reel
8000PCS/Reel (SOT-723,SOD-723)

10Reel/Inner Box
30KPCS/Inner Box
80KPCS/Inner Box (SOT-723,SOD-723)

Dim(Unit:mm)
460mm*400mm*420mm



12 Inner Box/Carton

360KPCS/Carton
960KPCS/Carton (SOT-723,SOD-723)